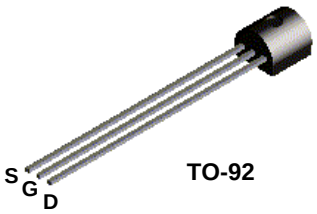
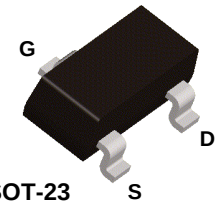
FAIRCHILD
SEMICONDUCTOR TM

J174
J175
J176
J177

MMBFJ175
MMBFJ176
MMBFJ177



TO-92



SOT-23
Mark: 6W / 6X / 6Y

P-Channel Switch

This device is designed for low level analog switching sample and hold circuits and chopper stabilized amplifiers. Sourced from Process 88.

Absolute Maximum Ratings*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V_{DG}	Drain-Gate Voltage	- 30	V
V_{GS}	Gate-Source Voltage	30	V
I_{GF}	Forward Gate Current	50	mA
T_J ,T_{stg}	Operating and Storage Junction Temperature Range	-55 to +150	°C

*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

NOTES:
1) These ratings are based on a maximum junction temperature of 150 degrees C.
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max		Units
		J174 - J177	*MMBFJ175	
P_D	Total Device Dissipation Derate above 25°C	350 2.8	225 1.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

*Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06."

P-Channel Switch
(continued)

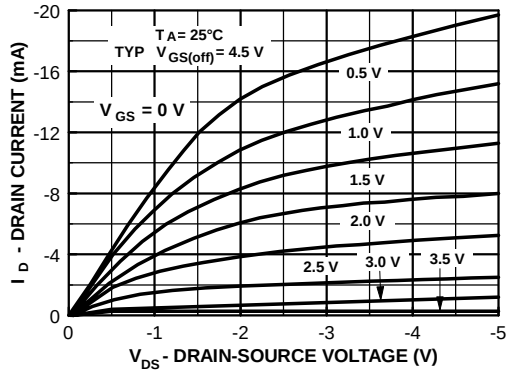
Electrical Characteristics
TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions		Min	Max	Units
OFF CHARACTERISTICS						
$B_{(BR)GSS}$	Gate-Source Breakdown Voltage	I_G = 1.0 µA, V_{DS} = 0		30		V
I_{GSS}	Gate Reverse Current	V_{GS} = 20 V, V_{DS} = 0			1.0	nA
$V_{GS(off)}$	Gate-Source Cutoff Voltage	V_{DS} = - 15 V, I_D = - 10 nA	**J174**	5.0	10	V
			J175	3.0	6.0	V
			J176	1.0	4.0	V
			J177	0.8	2.5	V
ON CHARACTERISTICS						
I_{DSS}	Zero-Gate Voltage Drain Current*	V_{DS} = - 15 V, I_{GS} = 0	**J174**	- 20	- 100	mA
			J175	- 7.0	- 60	mA
			J176	- 2.0	- 25	mA
			J177	- 1.5	- 20	mA
$r_{DS(on)}$	Drain-Source On Resistance	V_{DS} ≤ 0.1 V, V_{GS} = 0	**J174**		85	Ω
			J175		125	Ω
			J176		250	Ω
			J177		300	Ω

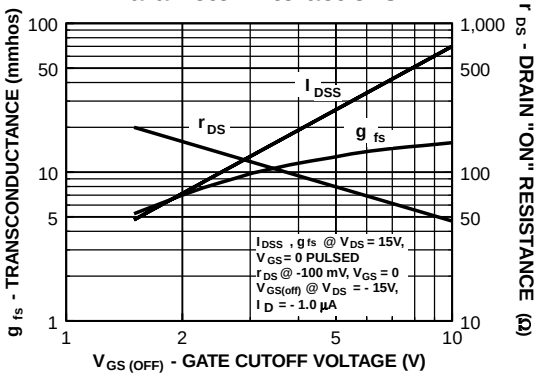
*Pulse Test: Pulse Width ≤ 300 µs, Duty Cycle ≤ 2.0%

Typical Characteristics

Common Drain-Source

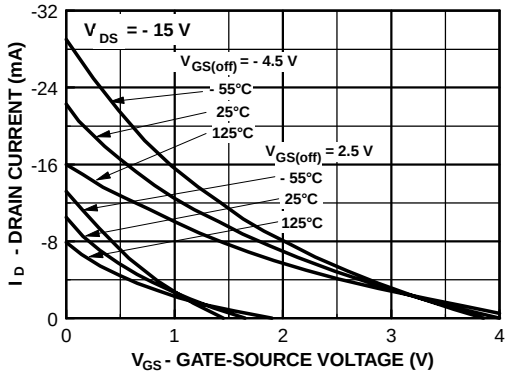


Parameter Interactions

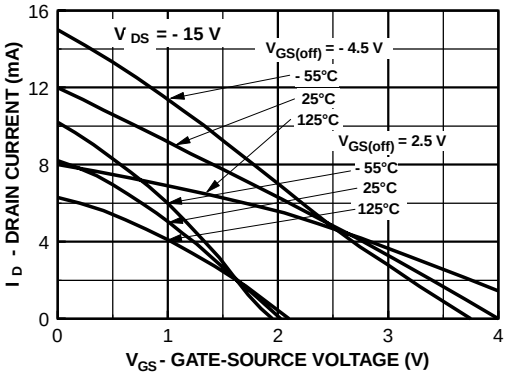


Typical Characteristics (continued)

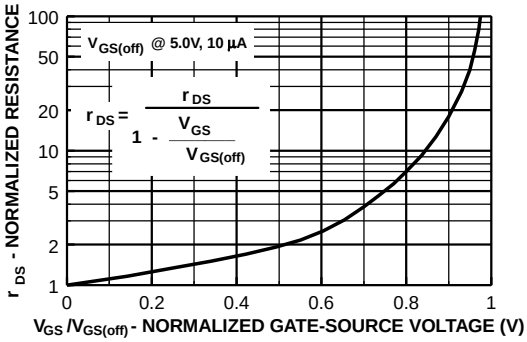
Transfer Characteristics



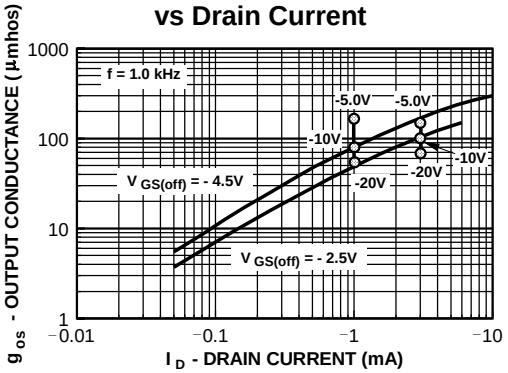
Transfer Characteristics



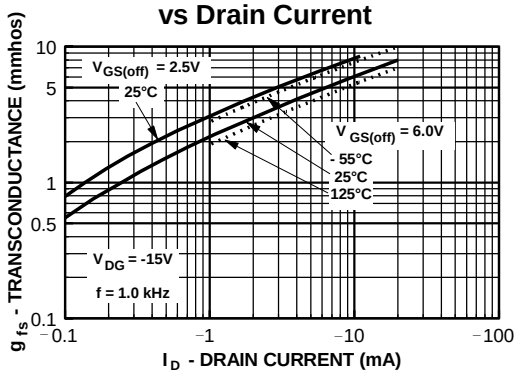
Normalized Drain Resistance vs Bias Voltage



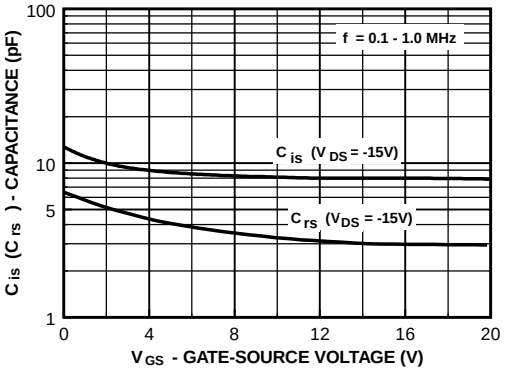
Output Conductance vs Drain Current



Transconductance vs Drain Current

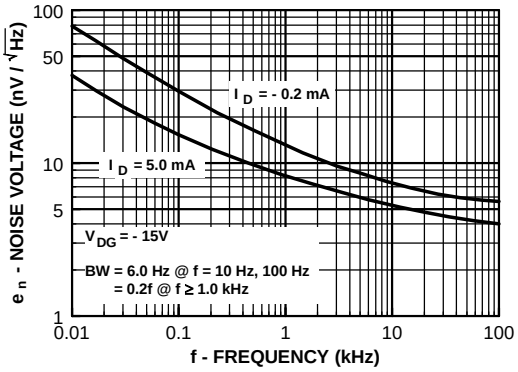


Capacitance vs Voltage

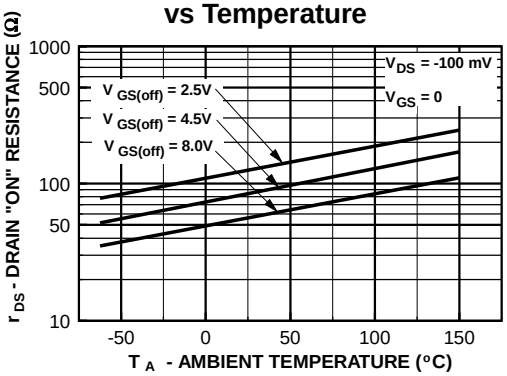


Typical Characteristics (continued)

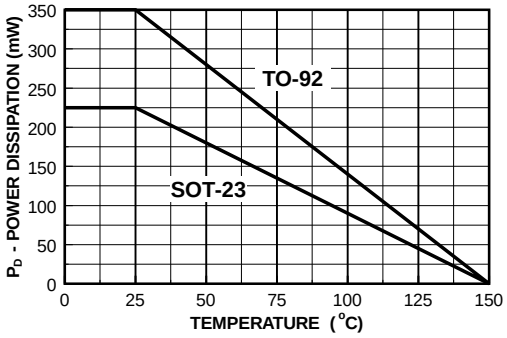
Noise Voltage vs Frequency



Channel Resistance vs Temperature



Power Dissipation vs Ambient Temperature



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